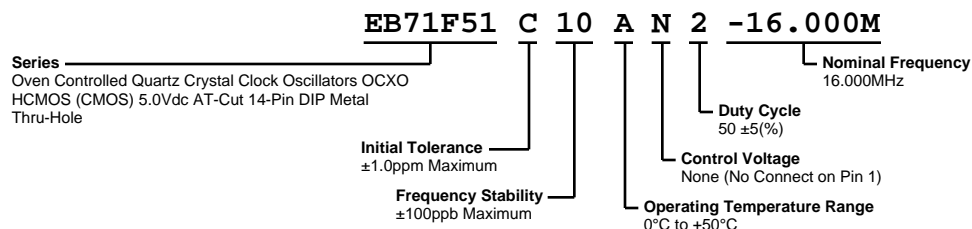


# EB71F51C10AN2-16.000M



## ELECTRICAL SPECIFICATIONS

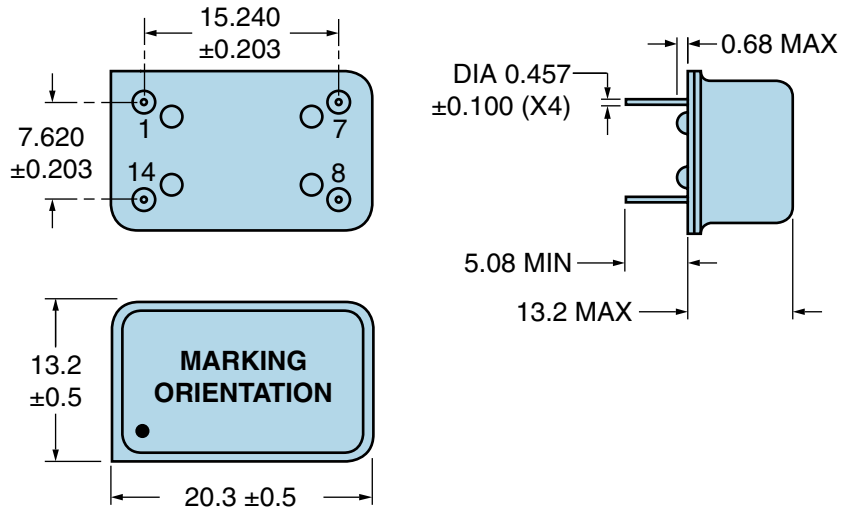
|  |   |
|--|---|
| Nominal Frequency                        | 16.000MHz   |
| Initial Tolerance                        | ±1.0ppm Maximum (Measured at nominal Vdd and Vc; at 25°C)   |
| Frequency Stability                      | ±100ppb Maximum (Measured at nominal Vdd and Vc)  |
| Frequency Stability vs. Input Voltage    | ±50ppb Maximum (Vdd ±5%)  |
| Frequency Stability vs. Load             | ±50ppb Maximum (Vload ±5%)  |
| Frequency Stability vs. Aging (1 Day)    | ±30ppb Maximum (after 72 hours of operation)  |
| Frequency Stability vs. Aging (1 Year)   | ±500ppb Maximum (after 72 hours of operation)   |
| Frequency Stability vs. Aging (10 Years) | ±3.0ppm Maximum (after 72 hours of operation)   |
| Operating Temperature Range              | 0°C to +50°C  |
| Supply Voltage                           | 5.0Vdc ±5%  |
| Warm Up Time                             | 3 Minutes Maximum (Referenced to ±500ppb of final frequency at 1 hour at 25°C)  |
| Power Consumption                        | 1.6 Watts Maximum at Steady State<br>2.5 Watts Maximum during Warm Up (Measured at 25°C)  |
| Output Voltage Logic High (Voh)          | Vdd-0.5Vdc Minimum (IOH = -8mA)   |
| Output Voltage Logic Low (Vol)           | 0.5Vdc Maximum (IOL = +8mA)   |
| Rise/Fall Time                           | 6nSec Maximum (Measured at 20% to 80% of waveform)  |
| Duty Cycle                               | 50 ±5(%) (Measured at 50% of waveform)  |
| Load Drive Capability                    | 15pF Maximum  |
| Output Logic Type                        | CMOS  |
| Control Voltage                          | None (No Connect on Pin 1)  |
| Control Voltage Range                    | 0.0Vdc to Vdd   |
| Frequency Deviation                      | ±5ppm Minimum (Referenced to Fo at Vc=2.5Vdc; Vdd=5.0Vdc; over Operating Temperature Range)   |
| Linearity                                | ±10% Maximum  |
| Transfer Function                        | Positive Transfer Characteristic  |
| Input Impedance                          | 10kOhms Typical   |
| Phase Noise                              | -95dBc/Hz at 10Hz Offset<br>-120dBc/Hz at 100Hz Offset<br>-135dBc/Hz at 1kHz Offset<br>-140dBc/Hz at 10kHz Offset (Measures at 12.800MHz) |
| Start Up Time                            | 10mSec Maximum  |
| Storage Temperature Range                | -55°C to +125°C   |

## ENVIRONMENTAL & MECHANICAL SPECIFICATIONS

|                              |                                      |
|------------------------------|--------------------------------------|
| Gross Leak Test              | MIL-STD-883, Method 1014 Condition C |
| Lead Integrity               | MIL-STD-883, Method 2004             |
| Mechanical Shock             | MIL-STD-202, Method 213 Condition C  |
| Resistance to Soldering Heat | MIL-STD-202, Method 210              |
| Resistance to Solvents       | MIL-STD-202, Method 215              |
| Solderability                | MIL-STD-883, Method 2003             |
| Temperature Cycling          | MIL-STD-883, Method 1010             |
| Vibration                    | MIL-STD-883, Method 2007 Condition A |

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## MECHANICAL DIMENSIONS (all dimensions in millimeters)

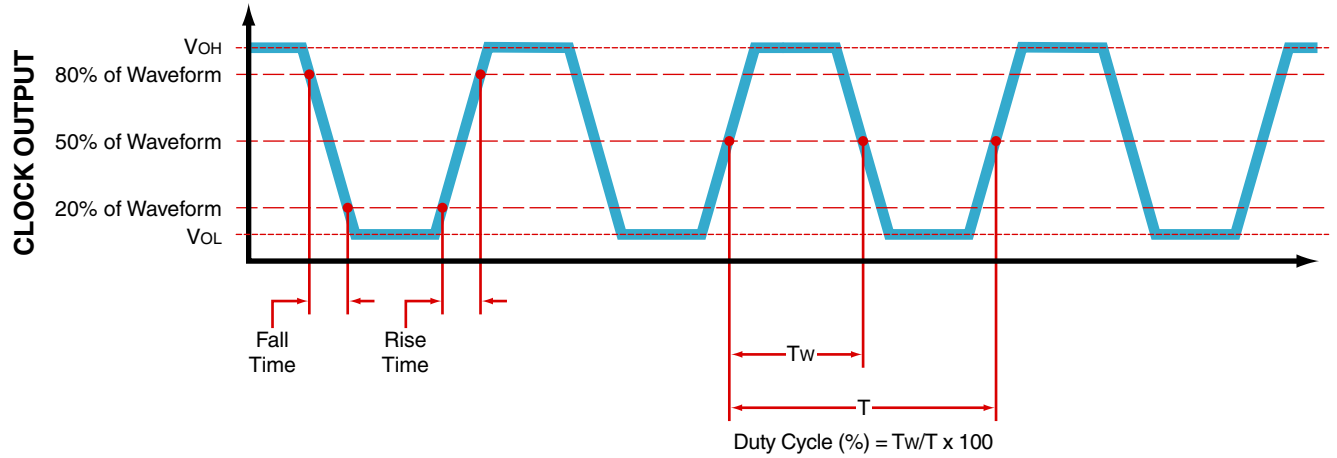


| PIN | CONNECTION     |
|-----|----------------|
| 1   | No Connect     |
| 7   | Case Ground    |
| 8   | Output         |
| 14  | Supply Voltage |

| LINE | MARKING  |
|------|--|
| 1    | <b>ECLIPTEK</b>  |
| 2    | <b>16.000M</b>   |
| 3    | <b>XXXXXX</b><br>XXXXXX=Ecliptek<br>Manufacturing Identifier |

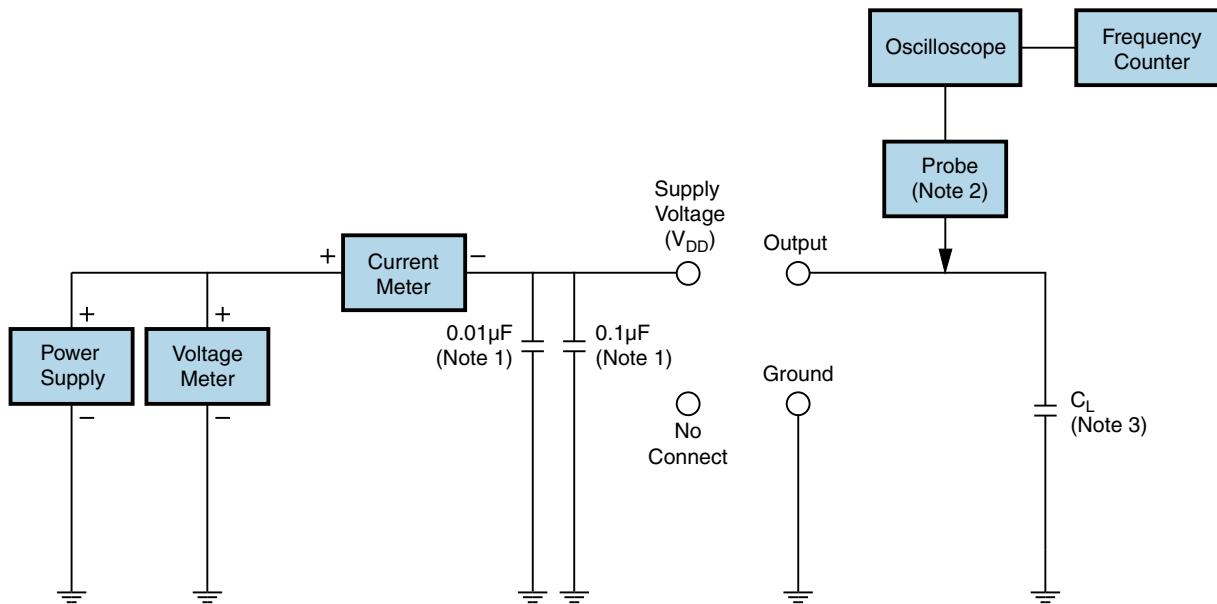
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## OUTPUT WAVEFORM



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## Test Circuit for No Connect Option



Note 1: An external 0.01µF ceramic bypass capacitor in parallel with a 0.1µF high frequency ceramic bypass capacitor close (less than 2mm) to the package ground and supply voltage pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value C<sub>L</sub> includes sum of all probe and fixture capacitance.

## Recommended Solder Reflow Methods



### Low Temperature Infrared/Convection 185°C

|  |   |
|--|---|
| <b>Ts MAX to TL (Ramp-up Rate)</b>         | 5°C/second Maximum  |
| <b>Preheat</b>                             |   |
| - Temperature Minimum (Ts MIN)             | N/A   |
| - Temperature Typical (Ts TYP)             | 150°C   |
| - Temperature Maximum (Ts MAX)             | N/A   |
| - Time (ts MIN)                            | 60 - 120 Seconds  |
| <b>Ramp-up Rate (TL to Tp)</b>             | 5°C/second Maximum  |
| <b>Time Maintained Above:</b>              |   |
| - Temperature (TL)                         | 150°C   |
| - Time (tL)                                | 200 Seconds Maximum   |
| <b>Peak Temperature (Tp)</b>               | 185°C Maximum   |
| <b>Target Peak Temperature (Tp Target)</b> | 185°C Maximum 2 Times   |
| <b>Time within 5°C of actual peak (tp)</b> | 10 seconds Maximum 2 Times  |
| <b>Ramp-down Rate</b>                      | 5°C/second Maximum  |
| <b>Time 25°C to Peak Temperature (t)</b>   | N/A   |
| <b>Moisture Sensitivity Level</b>          | Level 1   |
| <b>Additional Notes</b>                    | Temperatures shown are applied to body of device. Use this method only for product with the Gull Wing option. |

## Recommended Solder Reflow Methods



### Low Temperature Solder Bath (Wave Solder)

|  |  |
|--|--|
| <b><math>T_S</math> MAX to <math>T_L</math> (Ramp-up Rate)</b> | 5°C/second Maximum   |
| <b>Preheat</b>   |  |
| - Temperature Minimum ( $T_S$ MIN)                             | N/A  |
| - Temperature Typical ( $T_S$ TYP)                             | 150°C  |
| - Temperature Maximum ( $T_S$ MAX)                             | N/A  |
| - Time ( $t_s$ MIN)  | 30 - 60 Seconds  |
| <b>Ramp-up Rate (<math>T_L</math> to <math>T_P</math>)</b>     | 5°C/second Maximum   |
| <b>Time Maintained Above:</b>                                  |  |
| - Temperature ( $T_L$ )  | 150°C  |
| - Time ( $t_L$ )   | 200 Seconds Maximum  |
| <b>Peak Temperature (<math>T_P</math>)</b>                     | 245°C Maximum  |
| <b>Target Peak Temperature (<math>T_P</math> Target)</b>       | 245°C Maximum 1 Time / 235°C Maximum 2 Times   |
| <b>Time within 5°C of actual peak (<math>t_p</math>)</b>       | 5 seconds Maximum 1 Time / 15 seconds Maximum 2 Times  |
| <b>Ramp-down Rate</b>  | 5°C/second Maximum   |
| <b>Time 25°C to Peak Temperature (t)</b>                       | N/A  |
| <b>Moisture Sensitivity Level</b>                              | Level 1  |
| <b>Additional Notes</b>  | Temperatures shown are applied to back of PCB board and device leads only. Do not use this method for product with the Gull Wing option. |

### Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum. (Temperatures listed are applied to device leads only. This method can be utilized with both Gull Wing and Non-Gull Wing devices.)

### High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum. (Temperatures listed are applied to device leads only. This method can be utilized with both Gull Wing and Non-Gull Wing devices.)